

# 200mA / 30V Low $V_{\text{CE}}$ (sat) Digital transistors

# (with built-in resistors)

### DTD743EE / DTD743EM

#### Applications

Inverter, Interface, Driver

#### Feature

- 1. VCE (sat) is lower than the conventional products.
- 2. Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- 3. The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- 4. Only the on / off conditions need to be set for operation, making the device design easy.

#### Structure

NPN epitaxial plannar silicon transistor (Resistor built-in type)

#### Packaging specifications

	Package	EMT3	VMT3
	Packaging type	Taping	Taping
	Code	TL	T2L
Part No.	Basic ordering unit (pieces)	3000	8000
DTD723YE	·	0	-
DTD723YM		-	0

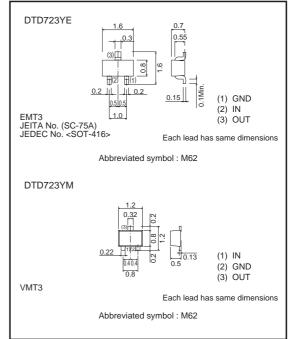
#### •Absolute maximum ratings (Ta=25°C)

Deremeter	Cumbol	Limits	Unit	
Parameter	Symbol	DTD743EE DTD743EM	Unit	
Supply voltage	Vcc	30	V	
Input voltage	Vin	-10 to +20	V	
Collector current *1	IC (max)	200	mA	
Power dissipation *2	Po	150	mW	
Junction temperature	Tj	150	Ĵ	
Storage temperature	Tstg	-55 to +150	C	

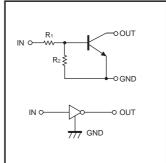
\*1 Characteristics of built-in transistor.

\*2 Each terminal mounted on a recommended land

#### •Dimensions (Unit : mm)



#### Inner circuit



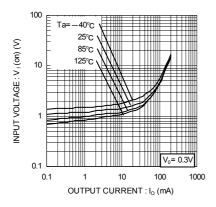
 $R_1=2.2k\Omega / R_2=10k\Omega$ 

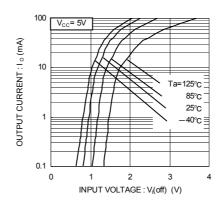
#### •Electrical characteristics (Ta=25°C)

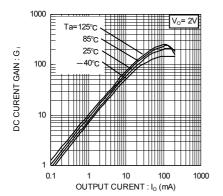
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Innut voltogo	VI(off)	-	-	0.5	v	Vcc= 5V, Io= 100µA
Input voltage	VI(on)	2.5	_	-	V	Vo=0.3V, Io=20mA
Output voltage	VO(on)	-	70	300	mV	lo/l=50mA / 2.5mA
Input current	h	-	-	1.4	mA	Vi= 5V
Output current	IO(off)	-	-	0.5	μA	Vcc=30V, VI=0V
DC current gain	Gı	115	-	-	-	Vo=2V, Io=100mA
Transition frequency *	f⊤	_	260	-	MHz	Vce=10V, Ie= -5mA, f=100MHz
Input resistance	R1	3.29	4.7	6.11	kΩ	_
Resistance ratio	R2/R1	0.8	1.0	1.2	-	_

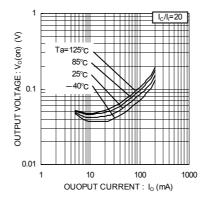
\* Characteristics of built-in transistor.

#### •Electrical characteristics curves









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